## Controlling and investigating domain and domain walls in PbTiO<sub>3</sub> ferroelectric thin films and heterostructures

Ludovica Tovaglieri,<sup>1</sup> Marios Hadjimichael,<sup>1,2</sup> Edoardo Zatterin,<sup>3</sup> Chia-Ping Su,<sup>4</sup> Iaroslav Gaponenko,<sup>1</sup> Chih-Ying Hsu,<sup>1,5</sup> Pau Torruella Besa,<sup>5</sup> Duncan T. L. Alexander,<sup>5</sup> Patrycja Paruch,<sup>1</sup> Alexandre Gloter,<sup>4</sup> Jean-Marc Triscone,<sup>1</sup> and Céline Lichtensteiger<sup>1</sup>

<sup>1</sup> Department of Quantum Matter Physics, University of Geneva, 24 Quai Ernest-Ansermet, 1211 Geneva, Switzerland <sup>2</sup> Department of Physics, University of Warwick, Coventry CV4 7AL, United Kingdom <sup>3</sup> ESRF, The European Synchroton, 71 Avenue des Martyrs, Grenoble 38000, France

<sup>4</sup> Université Paris-Saclay, CNRS, Laboratoire de Physique des Solides, Orsay 91405, France

<sup>5</sup> Electron Spectrometry and Microscopy Laboratory (LSME), Institute of Physics (IPHYS), Ecole Polytechnique Fédérale de Lausanne (EFPL), CH-1015 Lausanne, Switzerland

 $PbTiO_3$  is a material that exhibits a bulk paraelectric-ferroelectric phase transition at a critical temperature  $T_c$  of 765 K, with a polarisation that develops along the c-axis mostly due to ionic displacements. Theoretical studies of domain structures in  $PbTiO_3$  thin films have revealed complex phase diagrams with regions of distinct domain configurations as a function of different parameters [1].

We study the domain configuration in PbTiO<sub>3</sub> heterostructures, epitaxially grown on  $(110)_o$ oriented DyScO<sub>3</sub> substrates, with bottom and top SrRuO<sub>3</sub> electrodes using a combination of atomic force microscopy, laboratory and synchrotron x-ray diffraction, and high resolution scanning transmission electron microscopy. We observe a large asymmetry in the domain configuration due to the anisotropic strain imposed by the orthorhombic substrate, and we find that the periodicity of the domain wall deviates from the Kittel law. As the ferroelectric film thickness increases, the domain configuration evolves from flux-closure to an a/c-phase, with a larger scale arrangement of domains into superdomains [2].

Moreover, above a critical value of  $PbTiO_3$  thickness, we observe a modulation in the structure of the top  $SrRuO_3$  electrode, demonstrating the possibility of domain nano-engineering via structural coupling to ferroelastic domains [3].

[1] Schlom et al., Annu. Rev. Mater. Res., 37, 589-626 (2007).

[2] Lichtensteiger, ..., L.T. et al., APL Mater. 11, 061126 (2023).

[3] Lichtensteiger, ..., L.T. et al., APL Mater. 11, 101110 (2023).